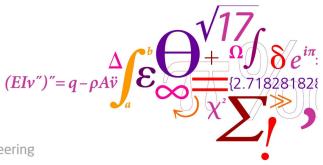


Lattice defects

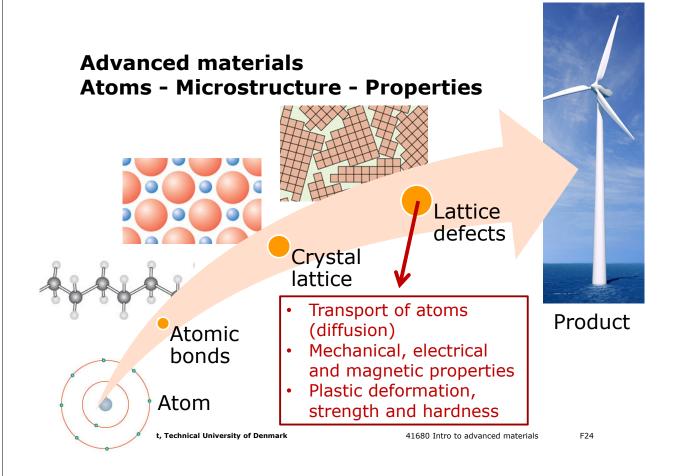
Is order everything?

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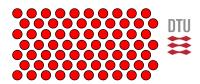
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Cubic lattices

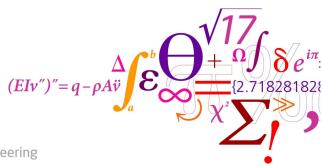
Simple cubic (sc)	Face-centered cubic (fcc)	Body-centered cubic (bcc)	
Elements	Al, Cu, Ni, Ag, Au, Pt, γ-Fe	$\alpha ext{-Fe, V, Nb, Ta, Cr,}$ Mo, W, K	
Atomic packing factor	74 %	68 %	
Packing of planes 3 DTU Conctruct, Technical University of	Close-packed planes	·	F24



Lattice defects

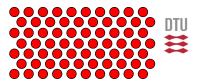
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"Crystals are like people, it is the defects in them, which make them interesting!"
(Colin Humphreys)



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Lattice defects

0-dimensional: point defects

vacancies, interstitials, substitutional atoms

1-dimensional: line defects

dislocations

2-dimensional: area (planar) defects interfaces (stacking faults, grain-, phase-, twin-boundaries, surfaces)

3-dimensional: volume (bulk) defects voids, pores, precipitates, inclusions, cracks

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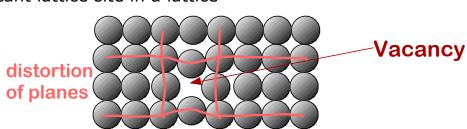
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Point defects

Vacancies

Vacant lattice site in a lattice



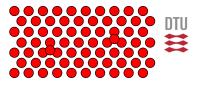
- Vacancies exist in thermal equilibrium
- Equilibrium density of vacancies

$$c_{V} = \frac{N_{V}}{N} = e^{-\frac{Q_{V}}{kT}}$$

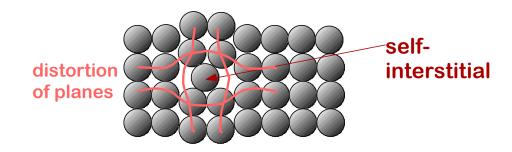
 N_V number of vacancies N number of lattice sites Q_V vacancy formation energy (G_V) $k=1.38\cdot 10^{-23}$ J/K Boltzmann constant

Concentration at melting point 10⁻⁴





• Atoms sitting on an interstitial site (between lattice sites)



- High formation energy:
 No self-interstitial atoms in thermal equilibrium in metals
- High mobility
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Lattice defects

0-dimensional: point defects vacancies, interstitials, substitutional atoms

1-dimensional: line defects

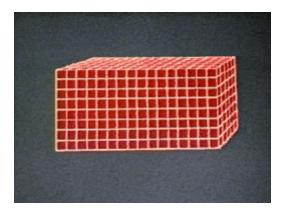
dislocations

2-dimensional: area (planar) defects interfaces (stacking faults, grain-, phase-, twin-boundaries, surfaces)

3-dimensional: volume (bulk) defects voids, pores, precipitates, inclusions, cracks



Motion of (edge) dislocation



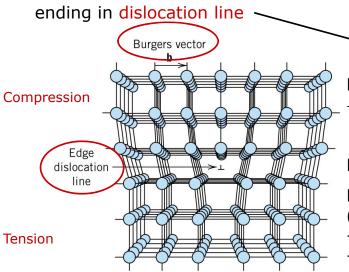
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Line defects Dislocations

Extra lattice plane inserted in crystal, not extending through all of the crystal (half-plane), ending in dislocation line.



Lattice disturbed along line → one-dimensional defect

Edge dislocation

Burgers vector (displacement vector)

- is a lattice vector
- defines slip direction

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Line defects Dislocations as carrier of plastic deformation

• Caterpillar technique





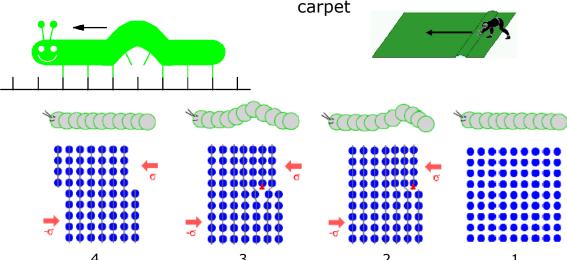
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Line defects Dislocations as carrier of plastic deformation

- Caterpillar technique
- same trick as moving a



plastic deformation proceeds

- atomic step by atomic step
- by movement of dislocations



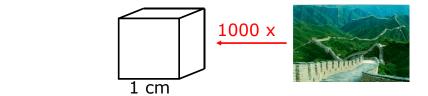
Line defects

Dislocation density

• Definition (dislocation line length per volume)

$$\rho = \frac{L}{V}$$

- SI unit $m/m^3 = m^{-2}$
- Whiskers containing a single (screw) dislocation
- Si wavers 10⁴ m⁻²
- Undeformed metals 10¹⁰ m⁻²
- Highly deformed metals 10¹⁶ m/m³
 - -Illustration:10 million km in a cm³



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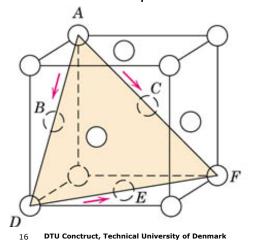


Dislocations and crystalline lattice

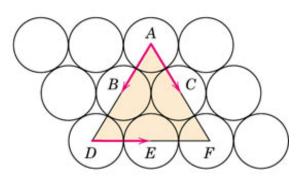


Slip systems in metals

- plastic deformation = dislocation motion = slip (or glide)



Example: fcc lattice

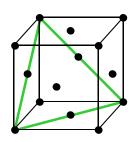


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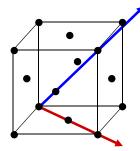
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Close-packed planes (hkl) and directions [uvw]





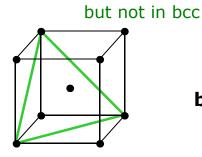
fcc



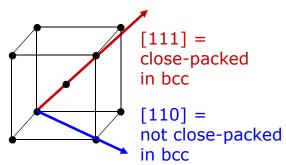
[111] = not close-packed in fcc

[110] = close-packed in fcc

(111) plane: close-packed in fcc,



bcc





Slip systems in metals

- plastic deformation = dislocation motion = slip (or glide)

Lattice	Examples	Close(st) packed planes (hkl)	Close(st) packed directions [uvw]	Slip systems
fcc	Al, Cu, Ag, Au, Ni, γ-Fe, 	{111} = close-packed	<110> face diagonals	4 x 3 = 12
bcc	Cr, W, α-Fe, 	{110} = not close- packed	<111> volume diagonals	6 x 2 = 12

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Lattice defects

0-dimensional: point defects

vacancies, interstitials, substitutional atoms

1-dimensional: line defects

dislocations

2-dimensional: area (planar) defects interfaces (stacking faults,

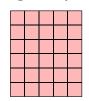
grain-, phase-, twin-boundaries, surfaces)

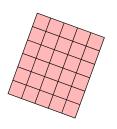
3-dimensional: volume (bulk) defects voids, pores, precipitates, inclusions, cracks



Microstructure - grains from solidification

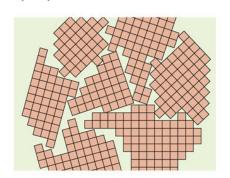
• Single crystals



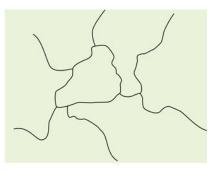


from a single nucleus

• Polycrystals



from many nuclei



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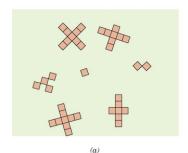
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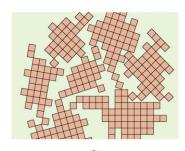
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Single crystal

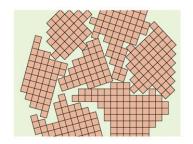
Planar defects

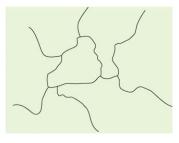
Grain boundaries in polycrystals





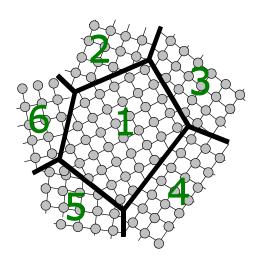
Nuclei form during solidification in melt





Nuclei grow and form grains

Planar defects Grain boundaries



Grain boundaries

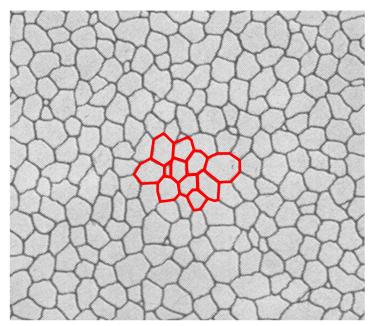
• Separate two grains i.e. two regions of same crystal structure, but of different crystallographic orientation

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Planar defects Grain boundaries



Grain size D

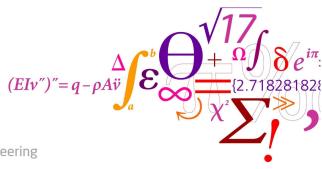
Surface area S Volume V

Boundary density

$$S_V = \frac{S}{V} \approx \frac{2}{D}$$



Intermezzo Stacking of close-packed planes



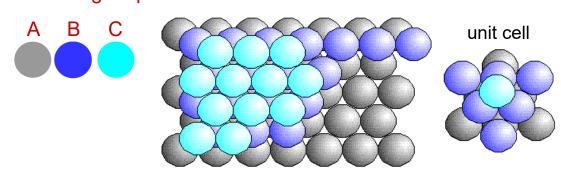
DTU Construct

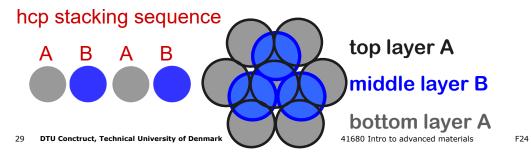
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Stacking sequences



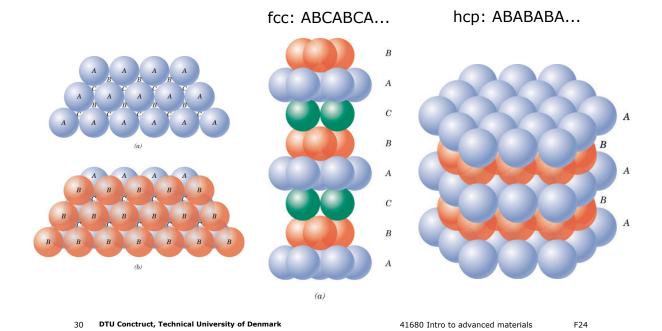
fcc stacking sequence





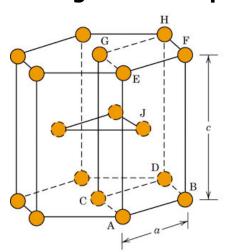


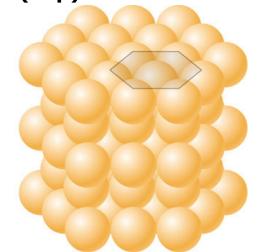
Stacking sequences





Hexagonal close-packed (hcp)





- Atomic packing factor 0.74
- Coordination number 12
- Examples: Mg, Co, Ti



Elements – crystal structures

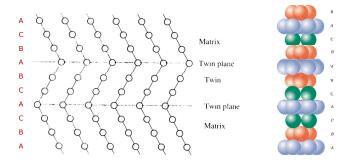
Н										He							
Li hcp	Ве	е								В	C cub	N	0	F	Ne		
Na hcp	Mg	Mg							Al	Si	Р	S	Cl	Ar			
K	Ca bcc	Sc fcc	Ti bcc	V	Cr	Mn	Fe fcc	Co fcc	Ni	Cu	Zn	Ga	Ge	As	Se	Br	Kr
Rb	Sr bcc	Y bcc	Zr bcc	Nb	Мо	Tc	Ru	Rh	Pd	Ag	Cd	In	Sn ttg	Sb	Те	I	Xe
Cs	Ва	L	Hf bcc	Та	W	Re	Os	Ir	Pt	Au	Hg	TI bcc	Pb	Bi	Ро	At	Rn
Fr	Ra	Α	Rf	Db	Sg	Bh	Hs	Mt	Ds	Rg	Cn	Nh	Fl	Мс	Lv	Ts	Og
		L	La fcc	Ce fcc	Pr bcc	Nd bcc	Pm bcc	Sm hcp	Eu	Gd bcc	Tb bcc	Dy bcc	Но	Er	Tm	Yb bcc	Lu
		Α	Ac	Th	Pa	U	Np	Pu	Am	Cm	Bk	Cf	Es	Fm	Md	No	Lr
	Cub	oic primitive					Face-centered cubic					Dia	mond	d (cu	bic)		
	Bod	dy-centered cubic					Hexagonal				Non	meta	als				



Planar defect

Twin boundaries in polycrystals

• Twin = mirrored crystalline lattice

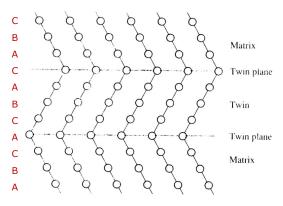


- Coherent boundaries on well-defined lattice planes (fcc {111})
- Twin formation causes shear
- Plastic deformation in non-cubic lattices ("tin cry")



Planar defects Twin boundaries

• Twin = mirror symmetry





Cu70-Zn30 wt%, α -phase, annealing twins

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Lattice defects

0-dimensional: point defects

vacancies, interstitials, substitutional atoms

1-dimensional: line defects

dislocations

2-dimensional: area (planar) defects

interfaces (stacking faults,

grain-, phase-, twin-boundaries, surfaces)

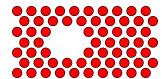
3-dimensional: volume (bulk) defects voids, pores, precipitates, inclusions, cracks



Volume defects

Self defects

- Clusters of point defects
- Pore = agglomerate of vacancies



• Requires many missing atoms!

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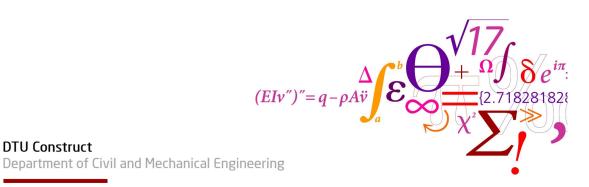
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Alloys

mixture of two or more elements with metallic bonding



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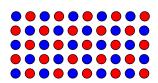


Alloys - three principle types

- Solid solutionsforeign atoms in crystal lattice
- Atoms unordered in same lattice

- Mixture of different metallic phases
- Distinct phases with different composition and possibly different lattices

Intermetallic compounds



 Atoms ordered in possibly different lattice

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Point defects in alloys



- •Interstitial atoms
 - ⇒ sitting between lattice sites
 - ⇒ interstitial solid solution
- Substitutional atoms
 - ⇒ substitute atoms on latt. sites
 - ⇒ substitutional solid solution
- Crystal structure maintained for solid solutions
- Alternatives
 - immiscibility
 - intermetallic compounds (new phase of own structure)

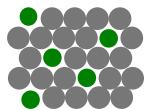




Point defects in alloys

Substitutional atoms

substitutional solid solution (e.g. Ni in Cu)



Hume-Rothery rules

Complete miscibility for substitutional solid solution requires:

- Same crystal structure
- Difference in atomic radius not more than 15%
- Similar electronegativity
- Same valence

Example: Cu and Ni

Otherwise

- Partial miscibility
- Immiscibility

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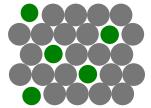
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Point defects in alloys

Substitutional atoms

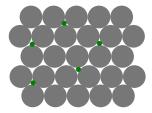
substitutional solid solution (e.g. Ni in Cu)



- Foreign atoms on regular lattice sites
- Hume-Rothery rules

Interstitial atoms

interstitial solid solution (e.g. C in Fe)



- Foreign atoms on interstitial sites
- Only small atoms in holes (as B, C, N, O)



Composition of binary alloys containing A and B

- Composition (weight percentage)
- Proper term: mass fraction

$$C_A = \frac{m_A}{m_A + m_B}$$

$$C_B = \frac{m_B}{m_A + m_B}$$

Conversion

$$m_A = n_A \mu_A$$

$$C_{A} = \frac{n_{A}\mu_{A}}{n_{A}\mu_{A} + n_{B}\mu_{B}} = \frac{C_{A}^{*}\mu_{A}}{C_{A}^{*}\mu_{A} + C_{B}^{*}\mu_{B}} \qquad C_{A}^{*} = \frac{C_{A}/\mu_{A}}{C_{A}/\mu_{A} + C_{B}/\mu_{B}}$$

- Composition (atomic percentage)
- Proper term: amount fraction

$$C_A^* = \frac{n_A}{n_A + n_B}$$

$$C_B^* = \frac{n_B}{n_A + n_B}$$

Conversion

$$\mu_A = m_A/n_A$$

$$C_A^* = \frac{C_A/\mu_A}{C_A/\mu_A + C_B/\mu_B}$$

m mass

n amount of substance (number of atoms) 49 μ molar mass (atomic mass, atomic weight) to to advanced materials

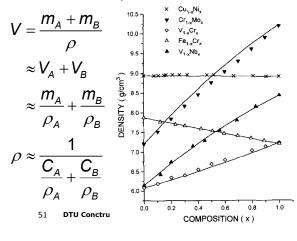
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Composition of binary alloys Applications



$$\rho = \frac{m}{V} = \frac{m_A + m_B}{V}$$

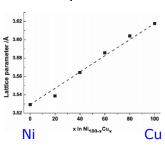
Naïve estimate: additivity of volumes



- Lattice constant a of solid solutions
 - Vegard's rule

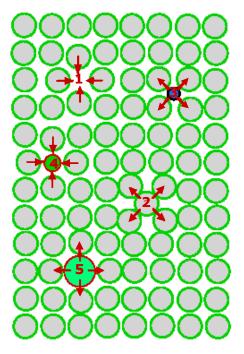
$$a_{ss} = C_A^* a_A + C_B^* a_B$$

- -Limited validity
- Example CuNi





Points defects



- local distortion of the lattice
- interaction
- external stress
- 1. Vacancy
- 2. self-interstitial
- 3. interstitial impurity
- 4. small substitutional impurity
- 5. large substitutional impurity

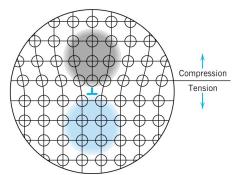
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Interaction: dislocations and point defects

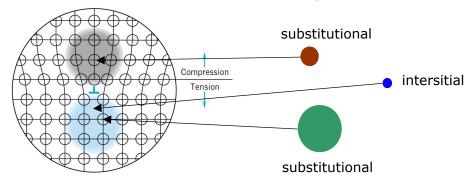


Which position is likely to be occupied by

- an interstitial atom
- a substitutional atom larger than the host ones
- a substitutional atom smaller than the host ones?



Interaction: dislocations and point defects



Which position is likely to be occupied by

- an interstitial atom
- a substitutional atom larger than the host ones
- a substitutional atom smaller than the host ones?

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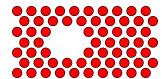
3-dimensional: volume (bulk) defects voids, pores, precipitates, inclusions, cracks



Volume defects

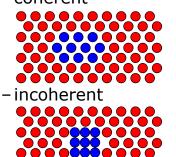
Self defects

- Clusters of point defects
- Pore = agglomerate of vacancies



 Requires many missing atoms! Alien defects

- Particles of second phase
- Precipitates
 - -coherent



Requires many atoms!

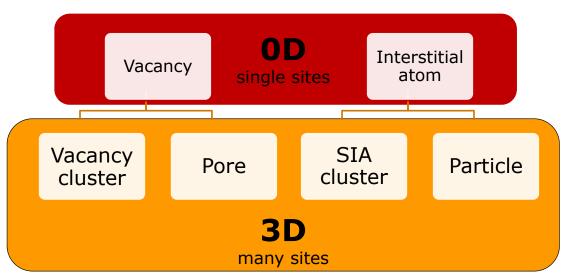
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Overview





Rôle of defects

- diffusion
- mechanical properties
- electrical properties
- magnetic properties
- plastic deformation
- strengthening mechanisms !!!
- various interactions e.g. interstitial atoms = obstacles to dislocation movement

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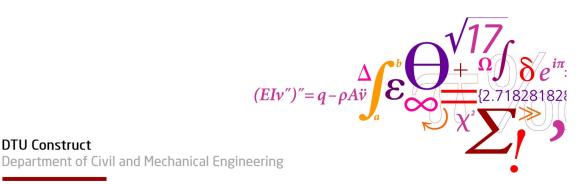
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Interstitial lattice sites

Where is space for foreign atoms?





Cubic lattices - comparison

	*	Close- packed direction	Neighbor closest to origin	Atomic dia- meter 2R	Atomic packing factor	Coordi- nation number	Examples
SC	1	<100>	[100] <i>a</i>	а	0.52	6	only α -Po
bcc	2	<111>	[111] <i>a</i> /2	$\sqrt{3}a/2$	0.68	8	Cr, W, V, Ta, α -Fe
fcc	4	<110>	[110] <i>a</i> /2	$\sqrt{2}a/2$	0.74	12	Al, Cu, Ag, Au, Ni, γ- Fe

* Number of atoms in unit cell

Lattice parameter a

Random close-packed spheres Ordered close-packed spheres 0.64

0.74

Only fcc is close-packed!

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Wanted Simple cubic lattice



1

 Coordination number (# nearest neighbors)

III • Ratio between edge length and atomic radius

$$a/R = 2$$

Atomic packing factor

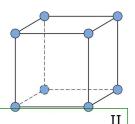
$$APF = \frac{\pi}{6} \approx 0.52$$

 Closest packed direction <100>

Closest packed planes

Close-packed

Not close-packed DTU Conctruct, Techn



Along edges

- X Atoms touch each other
- o Atoms do not touch each other
- Distance between centers

а

- Distance between neighbors

- Along face diagonals
 - o Atoms touch each other
 - X Atoms do not touch each other
 - Distance between centers

√2*a*

– Distance between neighbors $\sqrt{2}a - 2R$

- Along volume diagonals
 - o Atoms touch each other
 - X Atoms do not touch each other
 - Distance between centers

√3*a*

– Distance between neighbors $\sqrt{3}a - 2R$



Simple cubic lattice - Interstitial site



• Crystallographic planes

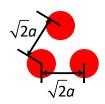
- Hard sphere model
- Interstitial site (hexahedral site)

$$2\mathbf{r}_{H} = \sqrt{3}\mathbf{a} - 2\mathbf{R}_{at} = 2\mathbf{R}_{at} \left(\sqrt{3} - 1\right)$$

$$r_{H}/R_{at} = 0.73$$

 $(100) \qquad (110)$ $a \qquad \qquad \sqrt{3}a$ $\sqrt{2}a$

(111)



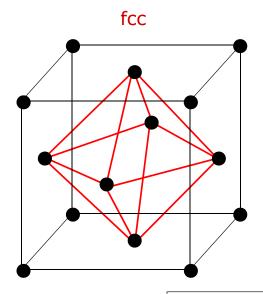
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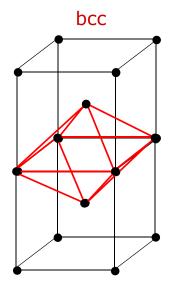
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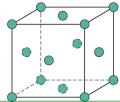
Interstitial sites - octahedral sites





Radius of interstitial site rRadius of host atoms $R_{\rm at}$

Wanted Face centered cubic lattice



- Atoms in unit cell
- 4
- Coordination number (# nearest neighbors)
- Along edges o Atoms touch each other



TT

- 12
 - X Atoms do not touch each other
 - Distance between centers
 - Distance between neighbors
- а a - 2R

III • Ratio between edge length and atomic radius

$$a/R = 4/\sqrt{2}$$

Atomic packing factor

$$APF = 4\frac{4\pi}{3} \left(\frac{\sqrt{2}}{4}\right)^3 = \frac{\pi\sqrt{2}}{6} \approx 0.74$$

- Closest packed direction <110>
- Closest packed planes

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- ★ Close-packed
- DTU Conctruct. Techn O Not close-packed

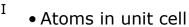
- Along face diagonals
 - X Atoms touch each other
 - Atoms do not touch each other
 - Distance between centers
- √2*a*/2
- Distance between neighbors
- Along volume diagonals
 - o Atoms touch each other
 - X Atoms do not touch each other
 - Distance between centers

- Distance between neighbors $\sqrt{3}a - 2$

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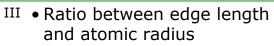
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Wanted **Body centered cubic lattice**



2

- Coordination number (# nearest neighbors)
- 8



$$a/R = 4/\sqrt{3}$$

Atomic packing factor

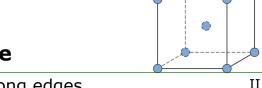
$$APF = 2\frac{4\pi}{3} \left(\frac{\sqrt{3}}{4}\right)^{\frac{2}{3}} = \frac{\pi\sqrt{3}}{8} \approx 0.68$$

- Closest packed direction <111>
- Closest packed planes



Close-packed

Not close-packed DTU Conctruct, Techn



- Along edges
 - o Atoms touch each other
 - X Atoms do not touch each other
 - Distance between centers

а a - 2R

- Distance between neighbors
- Along face diagonals
 - o Atoms touch each other ★ Atoms do not touch each other
 - Distance between centers

√2*a*

- Distance between neighbors $\sqrt{2}a 2R$
- Along volume diagonals X Atoms touch each other
 - Atoms do not touch each other
 - Distance between centers - Distance between neighbors

√3*a*/2



Group exercises

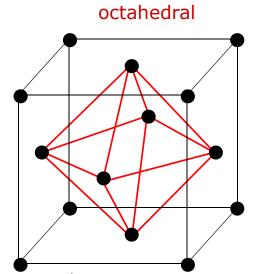
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Interstitial sites in fcc



number: 4 $r_{\rm O}/R_{\rm at} = 0.414$

Radius of interstitial site rRadius of host atoms $R_{\rm at}$

tetrahedral

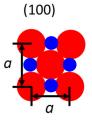
number: 8

 $r_{\rm T}/R_{\rm at} = 0.230$

$$a = 2R_{at} + 2r_O \rightarrow r_O = \frac{a}{2} - R_{at}$$



fcc



(110)



(111)

 $R_{at} = \sqrt{2}a/4$

 $\sqrt{2}a$

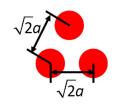
(100)



(111)

bcc





 $R_{at} = \sqrt{3}a/4$

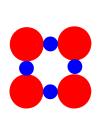
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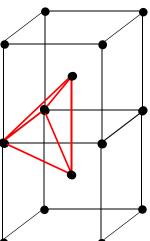
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Interstitial sites in bcc

octahedral



tetrahedral



number: 6

Radius of interstitial site r $r_{\rm O}/R_{\rm at} = 0.150$ Radius of host atoms R

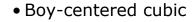
number: 12

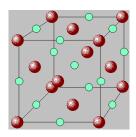
 $r_{\rm T}/R_{\rm at} = 0.290$ 41680 Intro to advanced materials

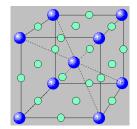


Interstitial lattice sites Octahedral interstitial sites

Face-centered cubic







- Number of sites in unit cell Number of sites in unit cell 1+12/4 = 4
- Number of atoms in unit cell
- 6/2+12/4=6
- Number of atoms in unit cell

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Interstitial lattice sites Overview

Lattice	Simple cubic	Body-centerd cubic	Face-centered cubic	
Atoms in uc	1	2	4	
Coordination	6	8	12	
APF	52 %	68 %	74 %	
Туре	Hexahedral	Octahedral	Octahedral	
-relative size	0.732	0.150	0.414	
-number in uc	1	6	4	
Sites/atom	1	3	1	